

V2.0.0 GaAs MMIC Low Noise Amplifier 0.05-20GHz

### **Features**

Single Biasing Voltage (Self Biased)

• Frequency: 0.05-20GHz

Small Signal Gain: 21.5dB Typical
 Gain Flatness: ±1.0dB Typical
 Noise Figure:1.6dB Typical

P1dB: 12dBm Typical

• Power Supply: +5V@71mA

• Input/Output:  $50\Omega$ 

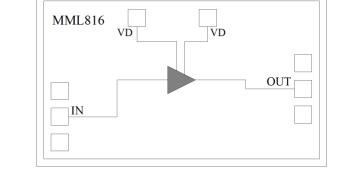
• Chip Size: 1.599 x 0.95 x 0.1mm

### **Typical Application**

- Test Instrumentation
- Microwave Radio & VSAT
- Military & Space
- Telecom Infrastructure
- Fiber Optics

## **Electrical Specifications**

TA = +25°C, VD = +5V, IDD = 71mA Typical



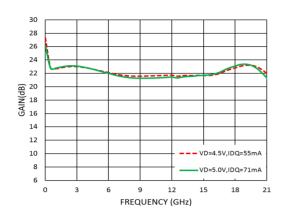
**Functional Block Diagram** 

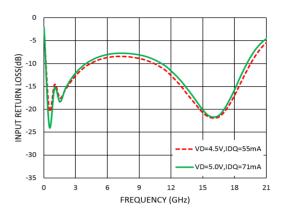
Parameters	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency	0.05		12	12		20	GHz
Small Signal Gain	20	21.5		20	21.5		dB
Gain Flatness		±1.0			±1.0		dB
Noise Figure		1.6			1.7		dB
P1dB - Output 1dB Compression	7	10		10	12		dBm
Psat - Saturated Output Power		13			13.5		dBm
OIP3 - Output Third Order Intercept		20			23		dBm
Input Return Loss		-8			-12		dB
Output Return Loss		-13			-15		dB

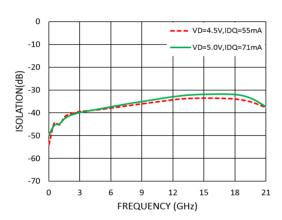


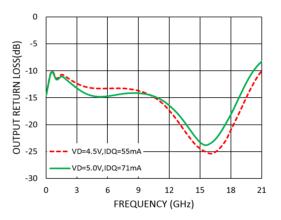
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# **Measurement Plots: S-parameters**

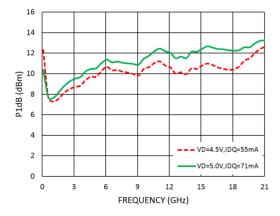




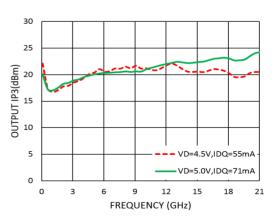




### **Measurement Plots: P1dB**



## **Measurement Plots: OIP3**

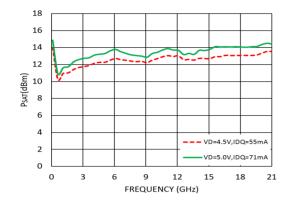


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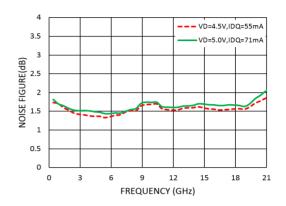


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## **Measurement Plots: PSAT**



# **Measurement Plots: Noise Figure**



# **Absolute Maximum Ratings**

Drain Bias Voltage (VD)	+6.5V
RF Input Power (RFIN)@(+5V)	+10dBm
Channel Temperature	220°C
Continuous Pdiss (T = 85 °C) (derate 7.8mW/°C above 85 °C)	0.7W
Thermal Resistance (channel to die bottom)	50°C/W
Operating Temperature	-40°C to +85 °C
Storage Temperature	-65°C to +150 °C

# **Typical Supply Current vs. VD**

VD (V)	IDD (mA)	
+4.5	55	
+5.0	71	



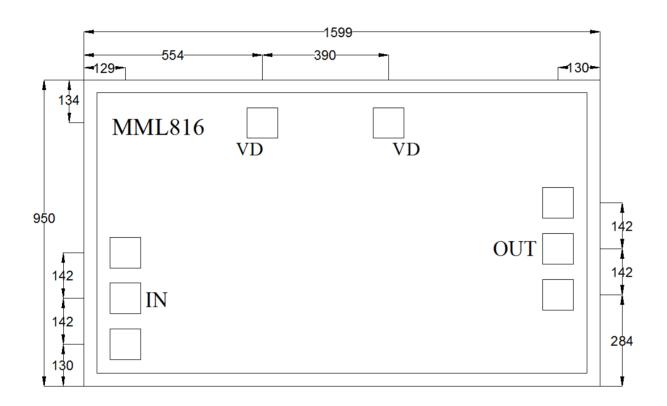
ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS



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## **Outline Drawing:**

All Dimensions in µm



#### Notes:

Die thickness: 100μm
 DC bond pad is 95\*95μm²

3. RF IN/OUT bond pad is 95\*95μm²
4. Bond pad metalization: Gold

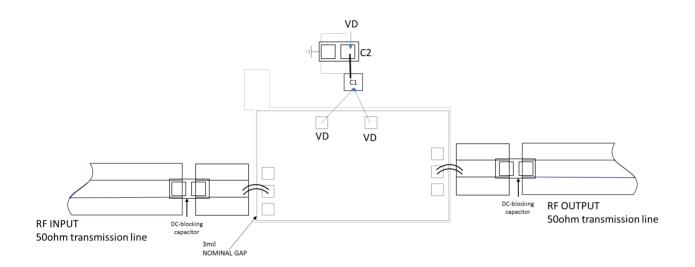
5. Backside metalization: Gold



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# **Assembly Drawing**



Item	Description	Item	Description
DC-blocking capacitor	0.1 μF Example: Passiveplus Part: 0402BB104KW500	C2	1μF Example: KYOCERA AVX Part:116XK102M100TT
C1	100pF Example: Presidio Part: MVB3030X103M2H5C1	C3	0.1μF Example: Murata Electronics Part:GRM033Z71C104KE14D (0201)

No	Function	Description
1	RF IN	Signal input terminal, connected to $50\Omega$ circuit; blocking capacitor required.
2	RF OUT	Signal output terminal, connected to $50\Omega$ circuit; blocking capacitor required.
3	VD	Drain Biases for the Amplifier. External bypass capacitors of 1µf and 100pf are required for these pads.
4	Die Bottom	Die bottom must be connected to RF and dc ground.

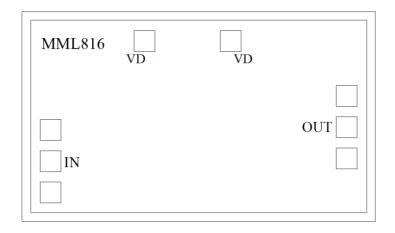
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# **Biasing and Operation**

#### **Turn ON procedure:**

- Connect GND to RF and dc ground.
- 2. Apply positive drain voltage VD and set to +5V.
- 3. Apply RF signal.

#### Turn OFF procedure:

- 1. Turn off the RF signal.
- 2. Turn off the positive drain voltage VD.

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